

**1-Line, Bi-directional, Ultra-low Capacitance Transient Voltage Suppressor**

**Features**

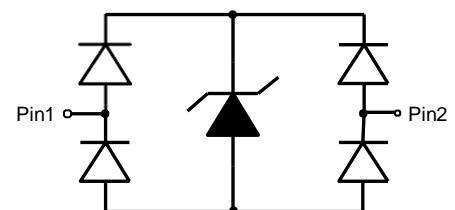
- Stand-off voltage: 18V Max.
- Transient protection for each line according to IEC61000-4-2(ESD): ±15kV (contact) IEC61000-4-5(surge): 4A (8/20µs)
- Ultra-low capacitance: CJ = 0.4pF typ.
- Ultra-low leakage current: IR < 1nA typ.
- Low clamping voltage: VCL = 10.0V typ. @ IPP = 16A (TLP)
- Solid-state silicon technology



**DFN1006-2**

**Applications**

- USB 2.0 and USB 3.0
- HDMI 1.3, HDMI 1.4 and HDMI 2.0
- SATA and eSATA interface
- DVI
- IEEE 1394
- Portable Electronics and Notebooks



**Pin configuration**

**Descriptions**

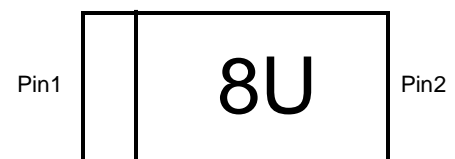
PESDR1811P1 is an ultra-low capacitance TVS (Transient Voltage Suppressor) designed to protect high speed data interfaces. It has been specifically designed to protect sensitive electronic components which are connected to data and transmission lines from over-stress caused by ESD (Electrostatic Discharge).

PESDR1811P1 incorporates one pair of ultra-low capacitance steering diodes plus a TVS diode.

PESDR1811P1 may be used to provide ESD protection up to ±15KV (contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 4A (8/20µs) according to IEC61000-4-5.

PESDR1811P1 is available in DFN1006-2 package.

Standard products are Pb-free and Halogen-free.



**Top View**

8U = Device code

**Order information**

Device	Package	Shipping
PESDR1811P1	DFN1006-2	10000/Tape & Reel

### Absolute maximum ratings

Parameter	Symbol	Rating	Unit
Peak pulse power ( $t_p = 8/20\mu s$ )	$P_{pk}$	40	W
Peak pulse current ( $t_p = 8/20\mu s$ )	$I_{PP}$	4	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 15$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 15$	
Junction temperature	$T_J$	125	$^{\circ}C$
Operating temperature	$T_{OP}$	-40~85	$^{\circ}C$
Lead temperature	$T_L$	260	$^{\circ}C$
Storage temperature	$T_{STG}$	-55~150	$^{\circ}C$

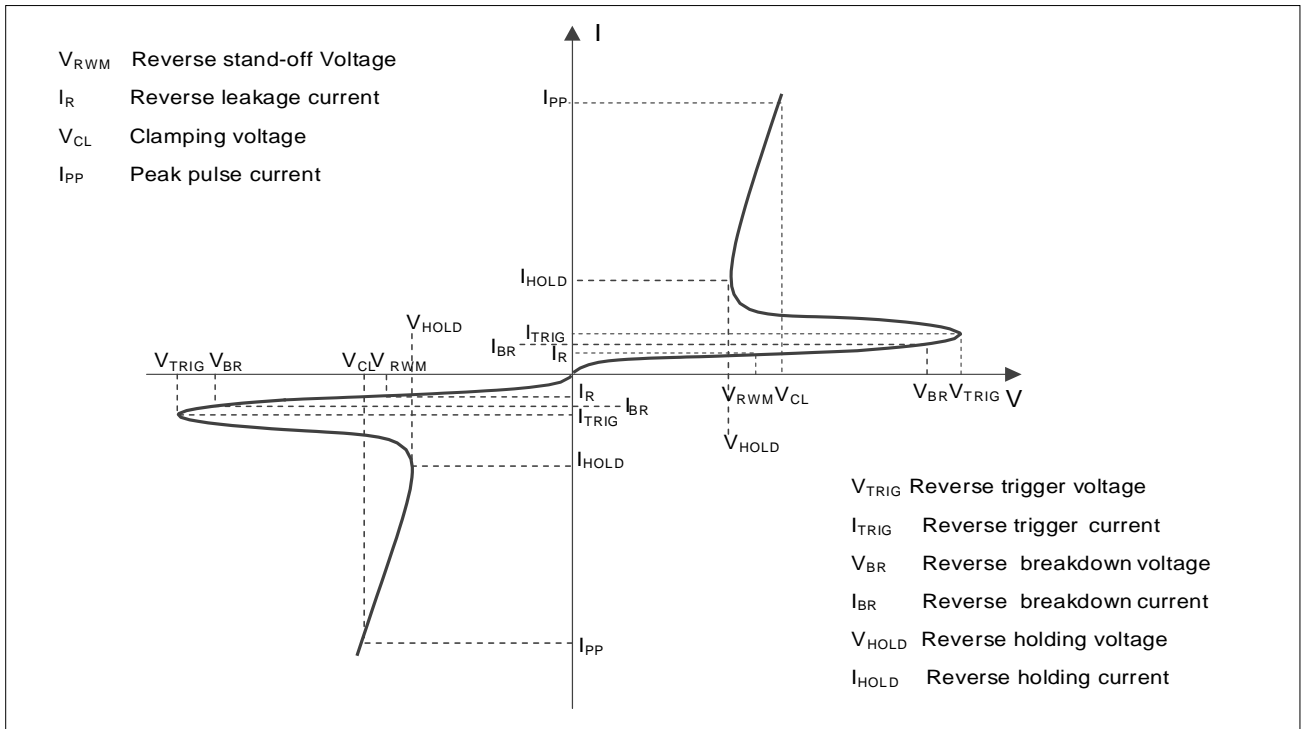
### Electrical characteristics ( $T_A = 25^{\circ}C$ , unless otherwise noted)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse maximum working voltage	$V_{RWM}$				$\pm 18$	V
Reverse leakage current	$I_R$	$V_{RWM} = 18V$		<1	50	nA
Reverse breakdown voltage	$V_{BR}$	$I_T = 1mA$	18.5			V
Clamping voltage <sup>1)</sup>	$V_{CL}$	$I_{PP} = 16A, t_p = 100ns$		10.0		V
Dynamic resistance <sup>1)</sup>	$R_{DYN}$			0.25		$\Omega$
Clamping voltage <sup>2)</sup>	$V_{CL}$	$V_{ESD} = 8kV$		10.0		V
Clamping voltage <sup>3)</sup>	$V_{CL}$	$I_{PP} = 1A, t_p = 8/20\mu s$		5	6	V
		$I_{PP} = 4A, t_p = 8/20\mu s$		9	10	V
Junction capacitance	$C_J$	$V_R = 0V, f = 1MHz$		0.4	0.55	pF

Notes:

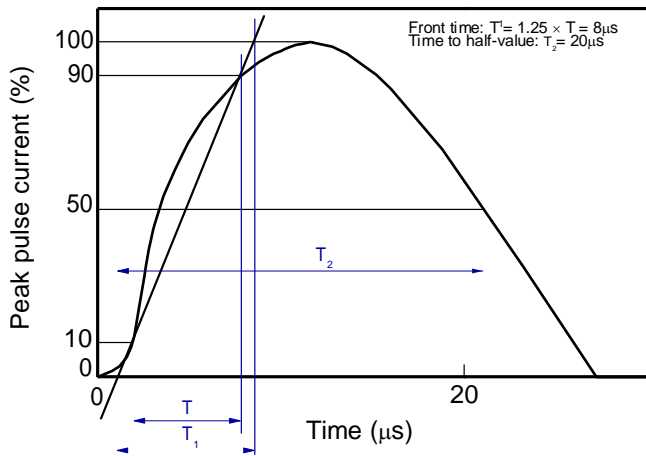
1. TLP parameter:  $Z_0 = 50\Omega$ ,  $t_p = 100ns$ ,  $t_r = 2ns$ , averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A.
2. Contact discharge mode, according to IEC61000-4-2.
3. Non-repetitive current pulse, according to IEC61000-4-5.

**Electrical characteristics (TA=25 °C, unless otherwise noted)**

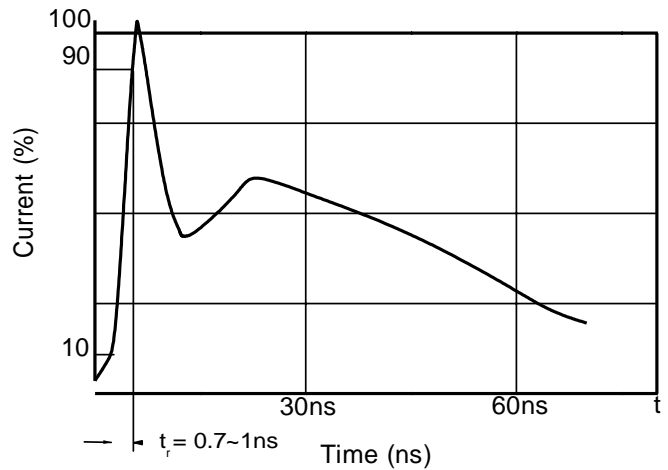


**Definitions of electrical characteristics**

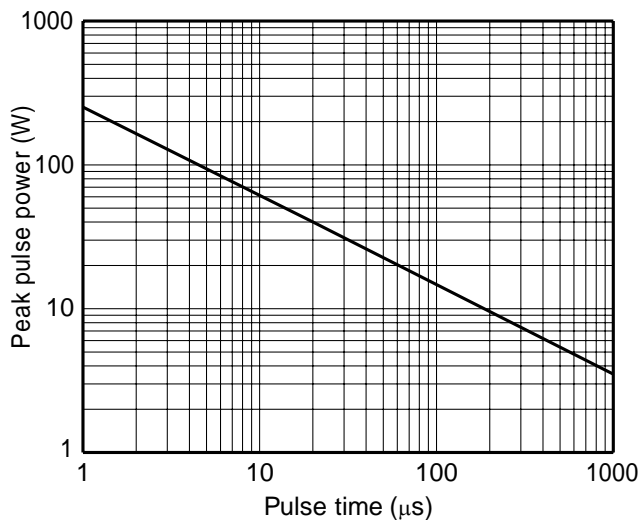
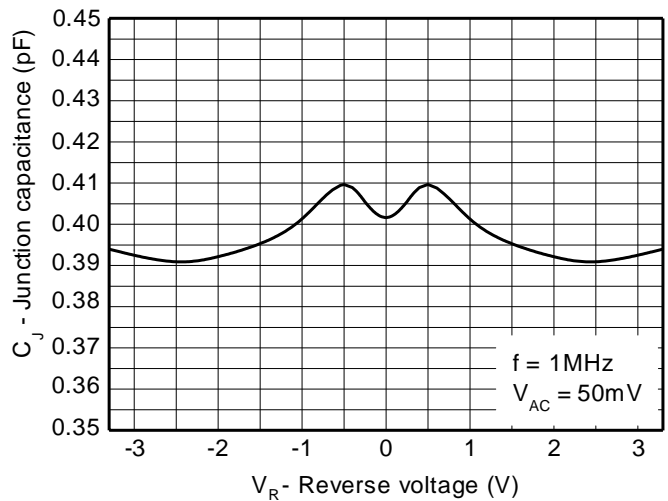
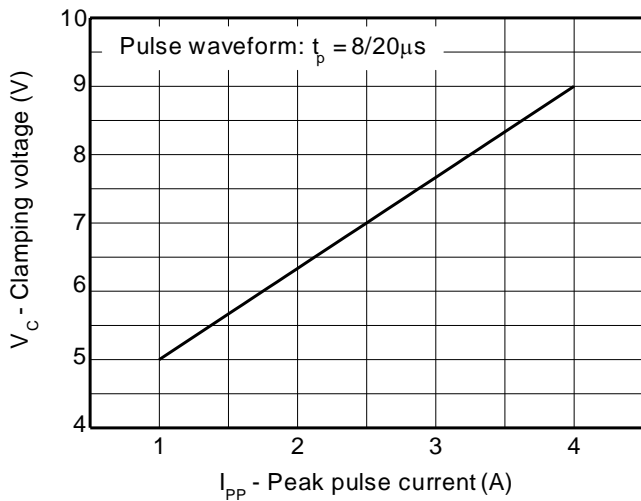
**Typical characteristics (TA = 25°C, unless otherwise noted)**



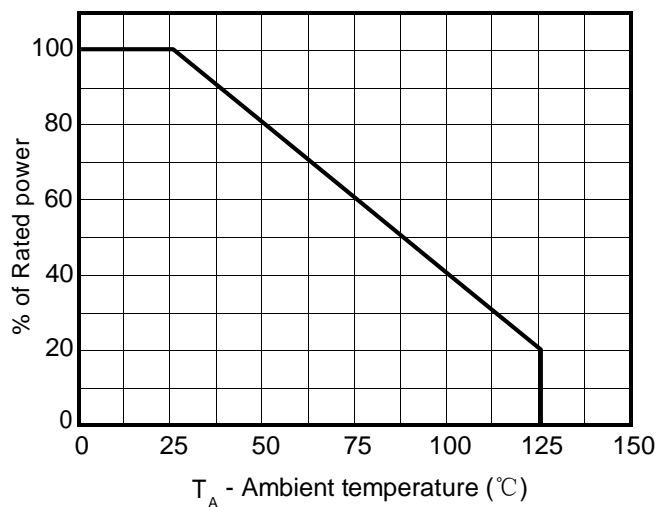
**8/20 $\mu\text{s}$  waveform per IEC61000-4-5**



**Contact discharge current waveform per IEC61000-4-2**

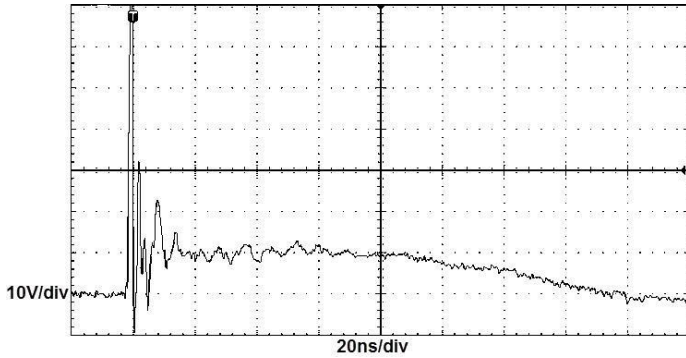


**Non-repetitive peak pulse power vs. Pulse time**

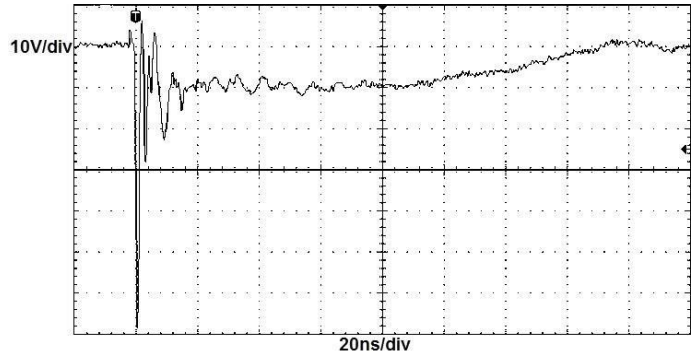


**Power derating vs. Ambient temperature**

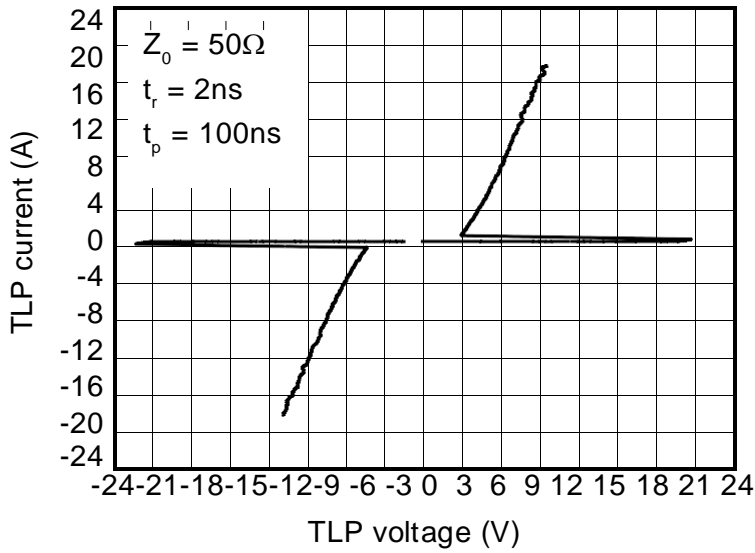
**Typical characteristics (TA = 25 °C, unless otherwise noted)**



**ESD clamping**  
**(+8kV contact discharge per IEC61000-4-2)**



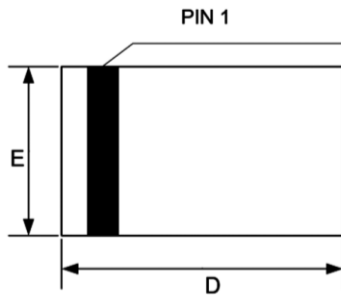
**ESD clamping**  
**(-8kV contact discharge per IEC61000-4-2)**



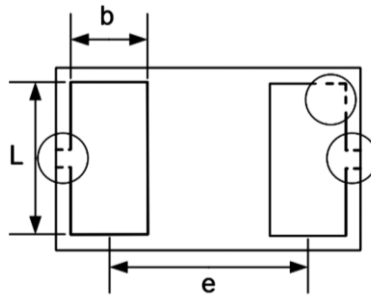
**TLP Measurement**

**PACKAGE OUTLINE DIMENSIONS**

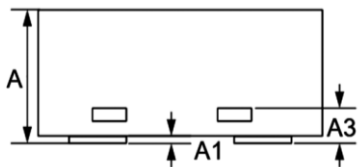
**DFN1006-2**



**Top View**



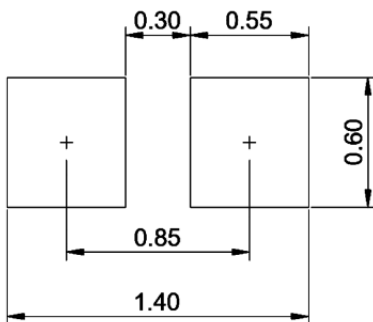
**Bottom View**



**Side View**

Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.340	0.450	0.530
A1	0.000	0.020	0.050
A3	0.125 Ref.		
D	0.950	1.000	1.075
E	0.550	0.600	0.675
b	0.200	0.250	0.300
L	0.450	0.500	0.550
e	0.650 BSC		

**Recommended PCB Layout (Unit: mm)**



**Notes:**

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

单击下面可查看定价，库存，交付和生命周期等信息

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